Physics II Electromagnetism (Lecture 14)

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Macroscopic Electric Fields In Dielectrics

In vacuum, the TRUE Electric field $E_{True} \equiv E_{vac}$ is unambiguously calculated which in general has contributions both from distant free as well as <u>bound</u> charge distributions $\rho_{\text{tot}} = \rho_f + \rho_b$.

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- \triangleright Within matter, the MICROSCOPIC Background Electric field E_{Micro} , due to ALL "elementary" charges (e.g., electrons, ions, nuclei, ...), is utterly complicated if not impossible to calculate. The net in-medium field is

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Then it becomes crucial to define a realistic MACROSCOPIC Field:

Definition

MACROSCOPIC Electric field: It is defined as the space average field over an arbitrary macroscopic volume V of matter which is large enough to contain a statistically large number ($\gtrsim 10^4\!-\!10^5)$ of atoms or molecules of that material, yet small enough compared to the dimensions of the material sample, in order to preserve all significant large-scale spatial variations in the field, i.e.,

$$
\boldsymbol{\mathcal{E}}(\boldsymbol{r})\equiv\langle\boldsymbol{E}_{\mathrm{True}}(\boldsymbol{r})\rangle_{\mathcal{V}}=\frac{1}{\mathcal{V}}\iiint\limits_{\mathcal{V}}\boldsymbol{E}_{\mathrm{True}}(\boldsymbol{r}'-\boldsymbol{r})d\boldsymbol{v}',
$$

where, for convenience, the integral is defined over a spherical region V .

Macroscopic Electric Fields In Dielectrics (contd.)

The entire dielectric medium can be thought of being composed of sufficiently finely grained spherical Averaging volumes (like, close-packing of marbles), such that each spherical volume contains a statistically large number of atoms or molecules.

▶ We henceforth work with Macroscopic Electric field $\mathcal{E}(r) \equiv \langle E_{True}(r) \rangle_{V}$, in dielectrics, which is a conservative field derivable from a coresponding Macroscopic Potential $\mathscr{V}(\mathbf{r}) = \langle V_{\text{True}}(\mathbf{r}) \rangle_{\mathcal{V}}$, such that

$$
\nabla \times \mathcal{E}(\mathbf{r}) = \nabla \times [-\nabla \mathscr{V}(\mathbf{r})] = 0 \quad \& \quad \oint_{\text{Loop}} \mathcal{E}(\mathbf{r}) \cdot d\mathbf{r} = 0.
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\n
$$
\implies \nabla \cdot \mathbf{D} = \rho_{\text{f}}
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\oiint_{S} \mathbf{D} \cdot d\mathbf{S} = \iiint_{\mathcal{V}} \nabla \cdot \mathbf{D} \, d\mathbf{v} = \iiint_{\mathcal{V}} \rho_f \, d\mathbf{v} = Q_{f, \text{encl}}
$$

where S is an arbitrary closed surface bounding a region of dielectric V with total enclosed free charge $Q_{f, \text{ encl}}$. 4 0 > 4 4 + 4 = > 4 = > = + + 0 4 0 + Modified Gauss's Law in Dielectrics: Summary

Modified Gauss's Law in Dielectrics: Summary

Warning!

 \triangleright Henceforth, we revert back to using the old symbol $E \longleftrightarrow E$ for the Macroscopic Electric Field keeping in mind that it is NOT the same as the True Electric Field E_{True} within a dielectric which in general includes the Microscopic Background Field E_{Micro} .

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► For free space (vacuum), they are equivalent, i.e., $\mathcal{E} \equiv \mathsf{E}_{\text{True}} \Rightarrow \mathsf{E}$.

Polarized Sphere

Example

Consider an <u>uncharged</u> dielectric sphere with a "frozen-in" Polarization $P = \frac{k}{r}\hat{r}$, where k is a constant. Find the Electric field as a function of r .

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▶ Method I: The bound volume & surface charge densities:

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\rho_b(r) = -\nabla \cdot \left(\frac{k}{r}\hat{\mathbf{r}}\right) = -\frac{1}{r^2}\frac{\partial}{\partial r}\left(r^2\frac{k}{r}\right) = -\frac{k}{r^2} \quad ; \quad \sigma_b = \left(\mathbf{P} \cdot \hat{\mathbf{r}}\right)_{r=R} = \frac{k}{R}
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 \blacktriangleright Total bound charge:

$$
Q_b = Q_b^{\text{(volume)}} + Q_b^{\text{(surface)}} = \iiint_V \rho_b(r) d\nu' + \oiint_S \sigma_b d\mathbf{a}'
$$

$$
= \int_0^R \left(-\frac{k}{r'^2}\right) 4\pi r'^2 dr' + \oiint_R \frac{k}{R} d\mathbf{a}' = -4\pi kR + 4\pi kR = 0
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▶ Field outside sphere $(r \geq R)$: Since $(Q_f + Q_b)_{\text{encl}} = 0$, then applying Gauss's Integral Law for E:

$$
\oiint_{S(r\geq R)} \mathbf{E} \cdot d\mathbf{a}' = \frac{1}{\epsilon_0} Q_{tot, \text{ encl}}(r) = 0
$$
\n
$$
\mathbf{E}_{r\geq R}(r) = 0
$$
\n
$$
(S(r\geq R)) \in \mathbb{R} \text{ and } S(r) = 0
$$

Field inside sphere $(r < R)$: σ_b does not contribute in the bulk, then using Gauss's Integral Law for E:

$$
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E(4\pi r^2) = \frac{1}{\epsilon_0} \int_{0}^{r} \left(-\frac{k}{r'^2} \right) 4\pi r'^2 dr' \implies \mathbf{E}(\mathbf{r}) = -\frac{k}{\epsilon_0 r} \hat{\mathbf{r}}
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 \blacktriangleright Method II: Since $Q_{f, \text{encl}} = 0$, then applying Modified Gauss's Law for D:

$$
\oiint_{S} \mathbf{D} \cdot d\mathbf{a}' = Q_{f, \text{ encl}} = 0 \implies \mathbf{D} = 0, \quad \forall r \text{ (everywhere)}
$$

$$
\mathsf{D} = \epsilon_0 \mathsf{E} + \mathsf{P} = 0 \quad \Longrightarrow \quad \mathsf{E}(\mathsf{r}) = -\frac{\mathsf{P}}{\epsilon_0} = \left\{ \begin{array}{ccc} 0 & \text{if} & r > R \\ -\frac{k}{\epsilon_0 r} \hat{\mathsf{r}} & \text{if} & r \leq R \end{array} \right.
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In Notice: Method II is much quicker without reference to bound charges!

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Example

A long straight wire, carrying uniform line charge density λ , is surrounded by rubber insulation out to radius a. Find the Electric Displacements and Electric fields everywhere.

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Example

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Gaussian surface

In Construct a coaxial cylindrical Gaussian surface S of radius s and length L:

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\oiint_{S} \mathbf{D} \cdot d\mathbf{S} = Q_{f; \text{encl}} = \lambda L
$$
\n
$$
D(2\pi sL) = \lambda L
$$
\n
$$
\mathbf{D(s)} = \left(\frac{\lambda}{2\pi s}\right) \hat{\mathbf{s}}, \quad \forall s \text{ (everywhere)}.
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Electric Field inside the cladding $(s \le a)$: Polarization P as well as the dielectric constant being unknown, E can not be calculated.

Electric Field outside the cladding $(s > a)$: Since Polarization P = 0, so $D \equiv \epsilon_0 E + P^{\gamma^0} \implies E(s) = \frac{1}{\epsilon_0} D(s) = \left(\frac{\lambda}{2\pi\epsilon_0}\right)$ $2\pi\epsilon_0$ $2\pi\epsilon_0$ $2\pi\epsilon_0$ $2\pi\epsilon_0$ s ˆs.

- \triangleright Consider an interface of two dielectrics media (1 & 2) with total surface charge density $\sigma_{tot} = \sigma_f + \sigma_b$ at the interface and total volume charge densities $\rho_{tot,1} = \rho_{f1} + \rho_{b1}$ and $\rho_{tot,2} = \rho_{f2} + \rho_{b2}$, in the respectively bulks.
- \triangleright Consider a pillbox-shaped Gaussian surface enclosing area S at the interface, with negligibly small width, $\epsilon \rightarrow 0$ in comparison with the base diameters.

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- \blacktriangleright Total enclosed free and bound charges within the Gaussian surface:

$$
Q_{f, \text{ end}} = \sigma_f S + \frac{\epsilon}{2} (\rho_{f1} + \rho_{f2}) S \xrightarrow{\epsilon \to 0} \sigma_f S,
$$

\n
$$
Q_{b, \text{ end}} = \sigma_b S + \frac{\epsilon}{2} (\rho_{b1} + \rho_{b2}) S \xrightarrow{\epsilon \to 0} \sigma_b S.
$$

Applying Gauss's Law for D:

$$
\lim_{\epsilon \to 0} \oiint_{S} \mathbf{D} \cdot d\mathbf{S} = (\mathbf{D}_1 \cdot \hat{\mathbf{n}}_1 + \mathbf{D}_2 \cdot \hat{\mathbf{n}}_2) S = \lim_{\epsilon \to 0} Q_{f, \text{encl}} = \sigma_f S
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$$
(\mathbf{D}_1 - \mathbf{D}_2) \cdot \hat{\mathbf{n}}_1 = D_{1\perp} - D_{2\perp} = \sigma_f.
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$$

 \blacktriangleright Macroscopic Electric field being conservative in nature, the circulation of E around any closed loop must vanish. Choosing a narrow rectangular loop of length L and vanishing end widths $\epsilon \rightarrow 0$ straddling across the interface,

$$
\lim_{\epsilon \to 0} \oint_{\text{Loop}} \mathbf{E} \cdot d\mathbf{l} = \mathbf{E}_1 \cdot \mathbf{L} + \mathbf{E}_2 \cdot (-\mathbf{L}) = 0
$$
\n
$$
(\mathbf{E}_1 - \mathbf{E}_2) \cdot \hat{\mathbf{n}}_{1||} = 0
$$
\n
$$
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Since $D = \epsilon_0 E + P$, it follows that $D_{||} = \epsilon_0 E_{||} + P_{||}$ and consequently

$$
D_{1||}-D_{2||}=P_{1||}-P_{2||}.
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 \triangleright Similarly, from $D_{\perp} = \epsilon_0 E_{\perp} + P_{\perp}$ $D_{11} - D_{21} = \epsilon_0 (E_{11} - E_{21}) + (P_{11} - P_{21})$

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 $\begin{bmatrix} \\ \\ \end{bmatrix}$

$$
D_{1\perp} - D_{2\perp} = \sigma_f,
$$

\n
$$
D_{1||} - D_{2||} = P_{1||} - P_{2||},
$$

\n
$$
P_{1\perp} - P_{2\perp} = -\sigma_b,
$$

\n
$$
E_{1\perp} - E_{2\perp} = \frac{1}{\epsilon_0} (\sigma_f + \sigma_b),
$$

\n
$$
E_{1||} = E_{2||},
$$

\n
$$
V_1 = V_2,
$$

\n
$$
\frac{\partial V_1}{\partial n} - \frac{\partial V_2}{\partial n} = \frac{1}{\epsilon_0} (\sigma_f + \sigma_b).
$$

 $\begin{bmatrix} 1 & 0 \\ 0 & 1 \end{bmatrix}$

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